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What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "<u>Embedded - Microcontrollers</u>"

Details	
Product Status	Active
Core Processor	ARM® Cortex®-M0+
Core Size	32-Bit Single-Core
Speed	32MHz
Connectivity	I ² C, IrDA, LINbus, SPI, UART/USART
Peripherals	Brown-out Detect/Reset, DMA, I2S, POR, PWM, WDT
Number of I/O	25
Program Memory Size	192KB (192K x 8)
Program Memory Type	FLASH
EEPROM Size	6K x 8
RAM Size	20K x 8
Voltage - Supply (Vcc/Vdd)	1.65V ~ 3.6V
Data Converters	A/D 10x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	32-LQFP
Supplier Device Package	32-LQFP (7x7)
Purchase URL	https://www.e-xfl.com/product-detail/stmicroelectronics/stm32l081kzt6

Introduction STM32L081xx

1 Introduction

The ultra-low-power STM32L081xx are offered in 32 and 48-pin packages. Depending on the device chosen, different sets of peripherals are included, the description below gives an overview of the complete range of peripherals proposed in this family.

These features make the ultra-low-power STM32L081xx microcontrollers suitable for a wide range of applications:

- Gas/water meters and industrial sensors
- Healthcare and fitness equipment
- · Remote control and user interface
- · PC peripherals, gaming, GPS equipment
- Alarm system, wired and wireless sensors, video intercom

This STM32L081xx datasheet should be read in conjunction with the STM32L0x1xx reference manual (RM0377).

For information on the ARM[®] Cortex[®]-M0+ core please refer to the Cortex[®]-M0+ Technical Reference Manual, available from the www.arm.com website.

Figure 1 shows the general block diagram of the device family.

STM32L081xx Description

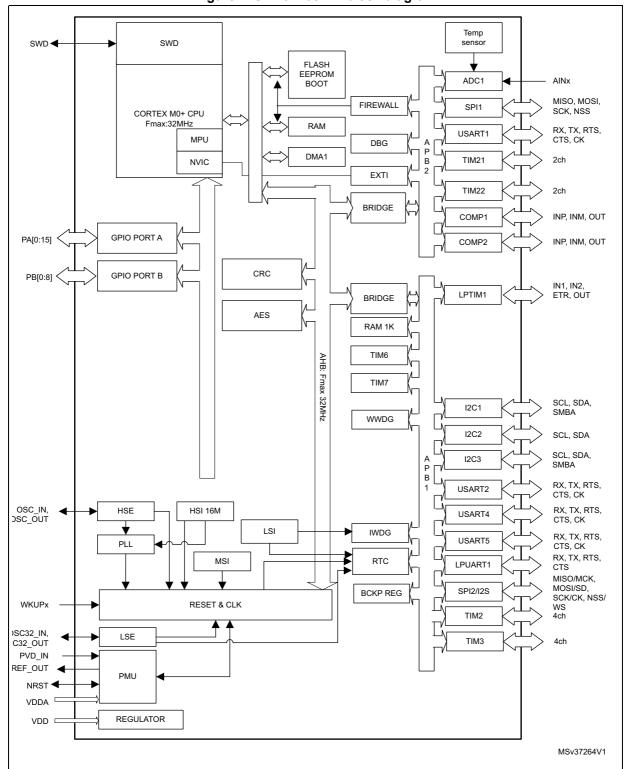


Figure 1. STM32L081xx block diagram

STM32L081xx Functional overview

3.16.3 Low-power universal asynchronous receiver transmitter (LPUART)

The devices embed one Low-power UART. The LPUART supports asynchronous serial communication with minimum power consumption. It supports half duplex single wire communication and modem operations (CTS/RTS). It allows multiprocessor communication.

The LPUART has a clock domain independent from the CPU clock. It can wake up the system from Stop mode using baudrates up to 46 Kbaud. The Wakeup events from Stop mode are programmable and can be:

- Start bit detection
- Or any received data frame
- Or a specific programmed data frame

Only a 32.768 kHz clock (LSE) is needed to allow LPUART communication up to 9600 baud. Therefore, even in Stop mode, the LPUART can wait for an incoming frame while having an extremely low energy consumption. Higher speed clock can be used to reach higher baudrates.

LPUART interface can be served by the DMA controller.

3.16.4 Serial peripheral interface (SPI)/Inter-integrated sound (I2S)

Up to two SPIs are able to communicate at up to 16 Mbits/s in slave and master modes in full-duplex and half-duplex communication modes. The 3-bit prescaler gives 8 master mode frequencies and the frame is configurable to 8 bits or 16 bits. The hardware CRC generation/verification supports basic SD Card/MMC modes.

The USARTs with synchronous capability can also be used as SPI master.

One standard I2S interfaces (multiplexed with SPI2) is available. It can operate in master or slave mode, and can be configured to operate with a 16-/32-bit resolution as input or output channels. Audio sampling frequencies from 8 kHz up to 192 kHz are supported. When the I2S interfaces is configured in master mode, the master clock can be output to the external DAC/CODEC at 256 times the sampling frequency.

The SPIs can be served by the DMA controller.

Refer to Table 12 for the differences between SPI1 and SPI2.

Table 12. SPI/I2S implementation

SPI features ⁽¹⁾	SPI1	SPI2
Hardware CRC calculation	Х	Х
I2S mode	-	Х
TI mode	Х	Х

^{1.} X = supported.

Pin descriptions STM32L081xx

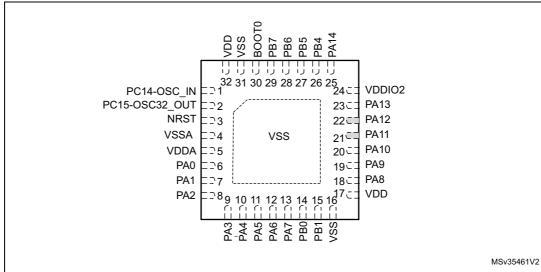


Figure 5. STM32L081xx UFQFPN32 pinout

- 1. The above figure shows the package top view.
- 2. I/O supplied by VDDIO2.

Table 13. Legend/abbreviations used in the pinout table

Nar	ne	Abbreviation	ion Definition			
Pin n	ame		ed in brackets below the pin name, the pin function during ne as the actual pin name			
		S	Supply pin			
Pin t	ype	I	Input only pin			
		I/O	Input / output pin			
		FT	5 V tolerant I/O			
		FTf	5 V tolerant I/O, FM+ capable			
I/O stru	ucture	TC	Standard 3.3V I/O			
		В	Dedicated BOOT0 pin			
		RST	Bidirectional reset pin with embedded weak pull-up resistor			
Not	es	Unless otherwise specified by a note, all I/Os are set as floating inputs during and after reset.				
Alternate functions Functions selected through GPIOx_AFR registers						
Pin functions	Additional functions	Functions directly selected	ed/enabled through peripheral registers			

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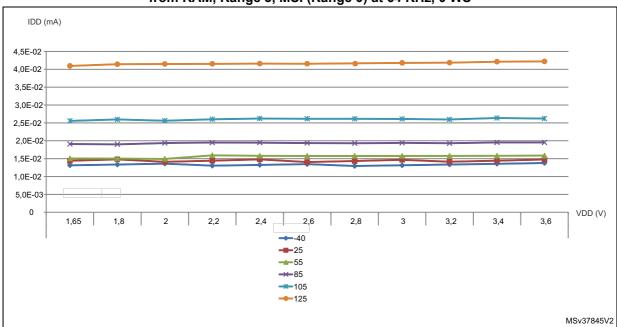


Figure 13. I_{DD} vs V_{DD} , at T_A = 25 °C, Low-power run mode, code running from RAM, Range 3, MSI (Range 0) at 64 KHz, 0 WS

Table 30. Current consumption in Low-power sleep mode

Symbol	Parameter		Condition		Тур	Max (1)	Unit
			MSI clock = 65 kHz, f _{HCLK} = 32 kHz, Flash memory OFF	$T_A = -40 \text{ to } 25^{\circ}\text{C}$	4,7	-	
				$T_A = -40 \text{ to } 25^{\circ}\text{C}$	17	24	
			MSI clock = 65 kHz,	T _A = 85°C	19,5	30	
	Supply current in Low-power sleep mode	All peripherals OFF, code executed from	f _{HCLK} = 32 kHz	T _A = 105°C	23	47	
				T _A = 125°C	32,5	70	
			MSI clock = 65 kHz, f _{HCLK} = 65 kHz	$T_A = -40 \text{ to } 25^{\circ}\text{C}$	17	24	
(LP Sleep)				T _A = 85°C	20	31	μA
	mode	Flash memory, V _{DD} from 1.65 to 3.6 V		T _A = 105°C	23,5	47	
				T _A = 125°C	32,5	70	
				$T_A = -40 \text{ to } 25^{\circ}\text{C}$	19,5	27	
				T _A = 55°C	20,5	28	
			MSI clock = 131kHz, f _{HCLK} = 131 kHz	T _A = 85°C	22,5	33	
			HOLK	T _A = 105°C	26	50	
				T _A = 125°C	35	73	

^{1.} Guaranteed by characterization results at 125 °C, unless otherwise specified.

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Table 33. Average current consumption during Wakeup

Symbol	parameter	System frequency	Current consumption during wakeup	Unit
		HSI	1	
		HSI/4	0,7	
I _{DD} (Wakeup from Stop)	Supply current during Wakeup from Stop mode	MSI clock = 4,2 MHz	0,7	
Glop)		MSI clock = 1,05 MHz	0,4	
		MSI clock = 65 KHz	0,1	mA
I _{DD} (Reset)	Reset pin pulled down	-	0,21	
I _{DD} (Power-up)	BOR on	-	0,23	
I _{DD} (Wakeup from	With Fast wakeup set	MSI clock = 2,1 MHz	0,5	
StandBy)	With Fast wakeup disabled	MSI clock = 2,1 MHz	0,12	

Low-speed external user clock generated from an external source

The characteristics given in the following table result from tests performed using a lowspeed external clock source, and under ambient temperature and supply voltage conditions summarized in Table 20.

Table 38. Low-speed external user clock characteristics⁽¹⁾

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
f _{LSE_ext}	User external clock source frequency		1	32.768	1000	kHz
V _{LSEH}	OSC32_IN input pin high level voltage		0.7V _{DD}	-	V _{DD}	V
V _{LSEL}	OSC32_IN input pin low level voltage	-	V _{SS}	-	0.3V _{DD}	V
t _{w(LSE)}	OSC32_IN high or low time		465	-	-	ns
$\begin{matrix} t_{r(LSE)} \\ t_{f(LSE)} \end{matrix}$	OSC32_IN rise or fall time		-	-	10	113
C _{IN(LSE)}	OSC32_IN input capacitance	-	-	0.6	-	pF
DuCy _(LSE)	Duty cycle	-	45	-	55	%
IL	OSC32_IN Input leakage current	$V_{SS} \leq V_{IN} \leq V_{DD}$	-	-	±1	μΑ

^{1.} Guaranteed by design, not tested in production

 V_{LSEH} 90% 10% V_{LSEL} t_{W(LSE)} T_{LSE} $f_{\mathsf{LSE_ext}}$ EXTERNAL OSC32 IN CLOCK SOURCE STM32Lxx ai18233c

Figure 17. Low-speed external clock source AC timing diagram

6.3.7 Internal clock source characteristics

The parameters given in *Table 41* are derived from tests performed under ambient temperature and V_{DD} supply voltage conditions summarized in *Table 20*.

High-speed internal 16 MHz (HSI16) RC oscillator

Table 41. 16 MHz HSI16 oscillator characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
f _{HSI16}	Frequency	V _{DD} = 3.0 V	-	16	-	MHz
TRIM ⁽¹⁾⁽²⁾	HSI16 user-	Trimming code is not a multiple of 16	-	± 0.4	0.7	%
TRIM	trimmed resolution	Trimming code is a multiple of 16	-	-	± 1.5	%
		V_{DDA} = 3.0 V, T_A = 25 °C	-1 ⁽³⁾	-	1 ⁽³⁾	%
	Accuracy of the factory-calibrated HSI16 oscillator	$V_{DDA} = 3.0 \text{ V}, T_A = 0 \text{ to } 55 ^{\circ}\text{C}$	-1.5	-	1.5	%
۸۵۵		V_{DDA} = 3.0 V, T_A = -10 to 70 °C	-2	-	2	%
ACC _{HSI16}		V_{DDA} = 3.0 V, T_{A} = -10 to 85 °C	-2.5	-	2	%
		V_{DDA} = 3.0 V, T_{A} = -10 to 105 °C	-4	-	2	%
		V _{DDA} = 1.65 V to 3.6 V T _A = -40 to 125 °C	-5.45	ı	3.25	%
t _{SU(HSI16)} ⁽²⁾	HSI16 oscillator startup time	•		3.7	6	μs
I _{DD(HSI16)} ⁽²⁾	HSI16 oscillator power consumption	-	ı	100	140	μΑ

^{1.} The trimming step differs depending on the trimming code. It is usually negative on the codes which are multiples of 16 (0x00, 0x10, 0x20, 0x30...0xE0).

- 2. Guaranteed by characterization results.
- 3. Guaranteed by test in production.

Figure 20. HSI16 minimum and maximum value versus temperature 4.009 3.00% 2.00% 1.65V min 0,00 3V typ 60 20 40 120 3.6V max 1.65V max ■ 3.6V min 4 00 -5.00% -6.00% MSv34791V1

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Table 43. MSI oscillator characteristics (continued)

Symbol	Parameter	Condition	Тур	Max	Unit
		MSI range 0	0.75	-	
		MSI range 1	1	-	
		MSI range 2	1.5	-	
I _{DD(MSI)} ⁽²⁾	MSI oscillator power consumption	MSI range 3	2.5	-	μΑ
טטי (MSI)		MSI range 4	4.5	-	
		MSI range 5	8	-	
		MSI range 6	15	-	
		MSI range 0	30	-	
		MSI range 1	20	-	
		MSI range 2	15	-	
		MSI range 3	10	-	
4	MSI oscillator startup time	MSI range 4	6	-	- μs
t _{SU(MSI)}		MSI range 5	5	-	
		MSI range 6, Voltage range 1 and 2	3.5	-	
		MSI range 6, Voltage range 3	5	-	
		MSI range 0	-	40	
		MSI range 1	-	20	
		MSI range 2	-	10	
		MSI range 3	-	4	
t _{STAB(MSI)} ⁽²⁾	MSI oscillator stabilization time	MSI range 4	-	2.5	μs
STAB(MSI)	Wor oscillator stabilization time	MSI range 5	-	2	μο
		MSI range 6, Voltage range 1 and 2	-	2	
		MSI range 3, Voltage range 3	-	3	
fo	Any range to range 5		-	4	MHz
f _{OVER(MSI)}	MSI oscillator frequency overshoot	Any range to range 6	-	6	IVII IZ

^{1.} This is a deviation for an individual part, once the initial frequency has been measured.

^{2.} Guaranteed by characterization results.

6.3.8 PLL characteristics

The parameters given in *Table 44* are derived from tests performed under ambient temperature and V_{DD} supply voltage conditions summarized in *Table 20*.

Table 44. PLL characteristics

Symbol	Parameter		Unit		
Symbol	Parameter	Min	Тур	Max ⁽¹⁾	Unit
f	PLL input clock ⁽²⁾	2	-	24	MHz
f _{PLL_IN}	PLL input clock duty cycle	45	-	55	%
f _{PLL_OUT}	PLL output clock	2	-	32	MHz
t _{LOCK}	PLL input = 16 MHz PLL VCO = 96 MHz	-	115	160	μs
Jitter	Cycle-to-cycle jitter	-		± 600	ps
I _{DDA} (PLL)	Current consumption on V _{DDA}	-	220	450	
I _{DD} (PLL)	Current consumption on V _{DD}	-	120	150	μΑ

^{1.} Guaranteed by characterization results.

6.3.9 Memory characteristics

RAM memory

Table 45. RAM and hardware registers

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
VRM	Data retention mode ⁽¹⁾	STOP mode (or RESET)	1.65	-	-	V

Minimum supply voltage without losing data stored in RAM (in Stop mode or under Reset) or in hardware registers (only in Stop mode).

Flash memory and data EEPROM

Table 46. Flash memory and data EEPROM characteristics

Symbol	Parameter	Conditions	Min	Тур	Max ⁽¹⁾	Unit
V _{DD}	Operating voltage Read / Write / Erase	-	1.65	-	3.6	V
t _{prog}	Programming time for word or half-page	Erasing	-	3.28	3.94	ms
		Programming	-	3.28	3.94	1115



^{2.} Take care of using the appropriate multiplier factors so as to have PLL input clock values compatible with the range defined by $f_{\text{PLL_OUT}}$.

Table 61. Temperature sensor characteristics

Symbol	Parameter	Min	Тур	Max	Unit
T _L ⁽¹⁾	V _{SENSE} linearity with temperature	-	±1	±2	°C
Avg_Slope ⁽¹⁾	Average slope	1.48	1.61	1.75	mV/°C
V ₁₃₀	Voltage at 130°C ±5°C ⁽²⁾	640	670	700	mV
I _{DDA(TEMP)} (3)	Current consumption	-	3.4	6	μA
t _{START} (3)	Startup time	-	-	10	110
T _{S_temp} ⁽⁴⁾⁽³⁾	ADC sampling time when reading the temperature	10	-	-	μs

- 1. Guaranteed by characterization results.
- 2. Measured at V_{DD} = 3 V ± 10 mV. V130 ADC conversion result is stored in the TS_CAL2 byte.
- 3. Guaranteed by design.
- 4. Shortest sampling time can be determined in the application by multiple iterations.

6.3.17 Comparators

Table 62. Comparator 1 characteristics

Symbol	Parameter	Conditions	Min ⁽¹⁾	Тур	Max ⁽¹⁾	Unit
V_{DDA}	Analog supply voltage	-	1.65		3.6	V
R _{400K}	R _{400K} value	-	-	400	-	kΩ
R _{10K}	R _{10K} value	-	-	10	-	V7.5
V _{IN}	Comparator 1 input voltage range	-	0.6	-	V_{DDA}	V
t _{START}	Comparator startup time	-	-	7	10	II.6
td	Propagation delay ⁽²⁾	-	-	3	10	μs
Voffset	Comparator offset	-	-	±3	±10	mV
d _{Voffset} /dt	Comparator offset variation in worst voltage stress conditions	$V_{DDA} = 3.6 \text{ V}, V_{IN+} = 0 \text{ V}, V_{IN-} = V_{REFINT}, T_A = 25 \text{ °C}$	0	1.5	10	mV/1000 h
I _{COMP1}	Current consumption ⁽³⁾	-	-	160	260	nA

^{1.} Guaranteed by characterization.

^{2.} The delay is characterized for 100 mV input step with 10 mV overdrive on the inverting input, the non-inverting input set to the reference.

^{3.} Comparator consumption only. Internal reference voltage not included.

The analog spike filter is compliant with I²C timings requirements only for the following voltage ranges:

- Fast mode Plus: $2.7 \text{ V} \leq \text{V}_{DD} \leq 3.6 \text{ V}$ and voltage scaling Range 1
- Fast mode:
 - 2 V \leq V_{DD} \leq 3.6 V and voltage scaling Range 1 or Range 2.
 - V_{DD} < 2 V, voltage scaling Range 1 or Range 2, C_{load} < 200 pF.

In other ranges, the analog filter should be disabled. The digital filter can be used instead.

Note: In Standard mode, no spike filter is required.

Table 65. I2C analog filter characteristics⁽¹⁾

Symbol	Parameter	Conditions	Min	Max	Unit
		Range 1		100 ⁽³⁾	ns
	are suppressed by the analog filter	Range 2	50 ⁽²⁾	-	
		Range 3	_	-	

- 1. Guaranteed by characterization results.
- 2. Spikes with widths below $t_{\text{AF}(\text{min})}$ are filtered.
- 3. Spikes with widths above $t_{\text{AF}(\text{max})}$ are not filtered

USART/LPUART characteristics

The parameters given in the following table are guaranteed by design.

Table 66. USART/LPUART characteristics

Symbol	Parameter	Conditions	Тур	Max	Unit
	Wakeup time needed to calculate the maximum USART/LPUART baudrate allowing to wake up from Stop mode	Stop mode with main regulator in Run mode, Range 2 or 3	-	8.7	μs
^t wuusart		Stop mode with main regulator in Run mode, Range 1	-	8.1	
WOOM		Stop mode with main regulator in low-power mode, Range 2 or 3	-	12	
		Stop mode with main regulator in low-power mode, Range 1	-	11.4	

I2S characteristics

Table 70. I2S characteristics⁽¹⁾

Symbol	Parameter	Conditions	Min	Max	Unit	
f _{MCK}	I2S Main clock output	-	256 x 8K	256xFs ⁽²⁾	MHz	
f	125 alaak fraguanay	Master data: 32 bits	-	64xFs	- MHz	
f _{CK}	I2S clock frequency	Slave data: 32 bits	-	64xFs		
D _{CK}	I2S clock frequency duty cycle	Slave receiver	30	70	%	
t _{v(WS)}	WS valid time	Master mode	-	15		
t _{h(WS)}	WS hold time	Master mode	11	-		
t _{su(WS)}	WS setup time	Slave mode	6	-		
t _{h(WS)}	WS hold time	Slave mode	2	-		
t _{su(SD_MR)}	Data input setup time	Master receiver	0	-		
t _{su(SD_SR)}	Data input setup time	Slave receiver	6.5	-	ns	
t _{h(SD_MR)}	Data input hold time	Master receiver	18	-	115	
t _{h(SD_SR)}	Data Input noid time	Slave receiver	15.5	-		
t _{v(SD_ST)}	Data output valid time	Slave transmitter (after enable edge)	-	77		
t _{v(SD_MT)}	Data output valid tillle	Master transmitter (after enable edge)		8		
t _{h(SD_ST)}	Data output hold time	Slave transmitter (after enable edge)	18	-		
t _{h(SD_MT)}	Data output noid time	Master transmitter (after enable edge)	1.5	-		

^{1.} Guaranteed by characterization results.

Note:

Refer to the I2S section of the product reference manual for more details about the sampling frequency (Fs), f_{MCK} , f_{CK} and D_{CK} values. These values reflect only the digital peripheral behavior, source clock precision might slightly change them. DCK depends mainly on the ODD bit value, digital contribution leads to a min of (I2SDIV/(2*I2SDIV+ODD) and a max of (I2SDIV+ODD)/(2*I2SDIV+ODD). Fs max is supported for each mode/condition.



^{2. 256}xFs maximum value is equal to the maximum clock frequency.

Table 71. LQFP48 - 48-pin, 7 x 7 mm low-profile quad flat package mechanical data

Cumbal	millimeters			inches ⁽¹⁾			
Symbol	Min	Тур	Max	Min	Тур	Max	
А	-	-	1.600	-	-	0.0630	
A1	0.050	-	0.150	0.0020	-	0.0059	
A2	1.350	1.400	1.450	0.0531	0.0551	0.0571	
b	0.170	0.220	0.270	0.0067	0.0087	0.0106	
С	0.090	-	0.200	0.0035	-	0.0079	
D	8.800	9.000	9.200	0.3465	0.3543	0.3622	
D1	6.800	7.000	7.200	0.2677	0.2756	0.2835	
D3	-	5.500	-	-	0.2165	-	
E	8.800	9.000	9.200	0.3465	0.3543	0.3622	
E1	6.800	7.000	7.200	0.2677	0.2756	0.2835	
E3	-	5.500	-	-	0.2165	-	
е	-	0.500	-	-	0.0197	-	
L	0.450	0.600	0.750	0.0177	0.0236	0.0295	
L1	-	1.000	-	-	0.0394	-	
k	0°	3.5°	7°	0°	3.5°	7°	
ccc	-	-	0.080	-	-	0.0031	

^{1.} Values in inches are converted from mm and rounded to 4 decimal digits.

7.2 LQFP32 package information

SEATING PLANE С 0.25 mm GAUGE PLANE С CCC D F D1 D3 16 \blacksquare ⊞ --₩ Ш -------____9 PIN 1 **IDENTIFICATION** 5V_ME_V2

Figure 34. LQFP32 - 32-pin, 7 x 7 mm low-profile quad flat package outline

1. Drawing is not to scale.

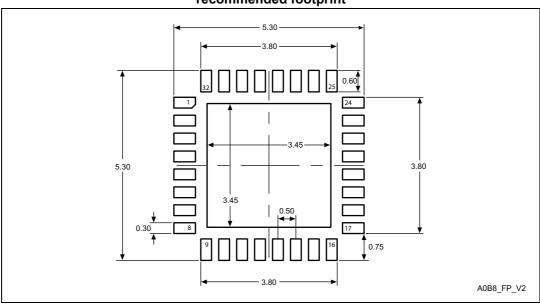
STM32L081xx Package information

Table 73. UFQFPN32 - 32-pin, 5x5 mm, 0.5 mm pitch ultra thin fine pitch quad flat package mechanical data

Symbol	millimeters			inches ⁽¹⁾			
	Min	Тур	Max	Min	Тур	Max	
А	0.500	0.550	0.600	0.0197	0.0217	0.0236	
A1	0.000	0.020	0.050	0.0000	0.0008	0.0020	
A3	-	0.152	-	-	0.0060	-	
b	0.180	0.230	0.280	0.0071	0.0091	0.0110	
D	4.900	5.000	5.100	0.1929	0.1969	0.2008	
D1	3.400	3.500	3.600	0.1339	0.1378	0.1417	
D2	3.400	3.500	3.600	0.1339	0.1378	0.1417	
E	4.900	5.000	5.100	0.1929	0.1969	0.2008	
E1	3.400	3.500	3.600	0.1339	0.1378	0.1417	
E2	3.400	3.500	3.600	0.1339	0.1378	0.1417	
е	-	0.500	-	-	0.0197	-	
L	0.300	0.400	0.500	0.0118	0.0157	0.0197	
ddd	-	-	0.080	-	-	0.0031	

^{1.} Values in inches are converted from mm and rounded to 4 decimal digits.

Figure 38. UFQFPN32 - 32-pin, 5x5 mm, 0.5 mm pitch ultra thin fine pitch quad flat recommended footprint



1. Dimensions are expressed in millimeters.

Package information STM32L081xx

Device marking for UFQFPN32

The following figure gives an example of topside marking versus pin 1 position identifier location.

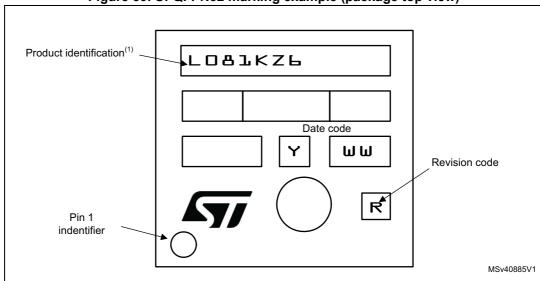


Figure 39. UFQFPN32 marking example (package top view)

Parts marked as "ES", "E" or accompanied by an Engineering Sample notification letter, are not yet
qualified and therefore not yet ready to be used in production and any consequences deriving from such
usage will not be at ST charge. In no event, ST will be liable for any customer usage of these engineering
samples in production. ST Quality has to be contacted prior to any decision to use these Engineering
samples to run qualification activity.

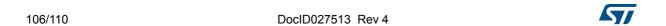


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Package information STM32L081xx

7.4.1 Reference document

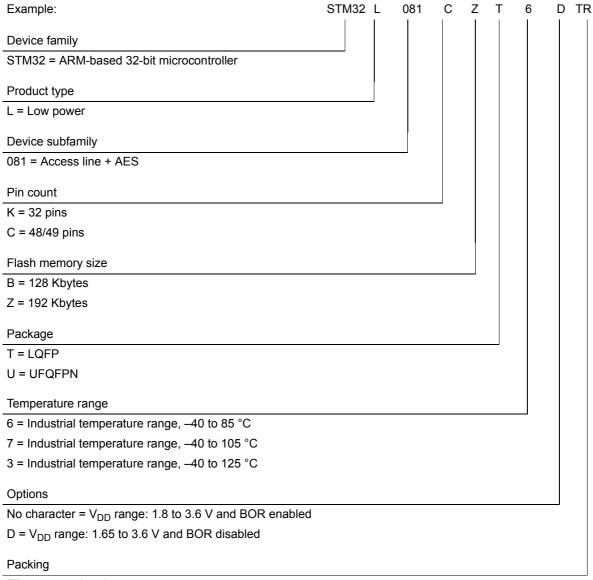
JESD51-2 Integrated Circuits Thermal Test Method Environment Conditions - Natural Convection (Still Air). Available from www.jedec.org.



STM32L081xx Part numbering

8 Part numbering

Table 75. STM32L081xx ordering information scheme



TR = tape and reel

No character = tray or tube

For a list of available options (speed, package, etc.) or for further information on any aspect of this device, please contact your nearest ST sales office.

STM32L081xx Revision history

Table 76. Document revision history

Date	Revision	Changes
03-May-2016	4	Added UFQFPN32 package. Updated number of communication interfaces and GPIOs on cover page.